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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	32MHz
Connectivity	I²C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, LCD, POR, PWM, WDT
Number of I/O	25
Program Memory Size	7KB (4K x 14)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	256 x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 11x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	28-SSOP (0.209", 5.30mm Width)
Supplier Device Package	28-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16f1933t-i-ss

TABLE 1-2: PIC16(L)F1933 PINOUT DESCRIPTION (CONTINUED)

Name	Function	Input Type	Output Type	Description
RC6/TX/CK/CCP3/P3A/SEG9	RC6	ST	CMOS	General purpose I/O.
	TX	—	CMOS	USART asynchronous transmit.
	CK	ST	CMOS	USART synchronous clock.
	CCP3	ST	CMOS	Capture/Compare/PWM.
	P3A	—	CMOS	PWM output.
	SEG9	—	AN	LCD Analog output.
RC7/RX/DT/P3B/SEG8	RC7	ST	CMOS	General purpose I/O.
	RX	ST	—	USART asynchronous input.
	DT	ST	CMOS	USART synchronous data.
	P3B	—	CMOS	PWM output.
	SEG8	—	AN	LCD Analog output.
RE3/$\overline{\text{MCLR}}$/V_{PP}	RE3	TTL	—	General purpose input.
	$\overline{\text{MCLR}}$	ST	—	Master Clear with internal pull-up.
	V_{PP}	HV	—	Programming voltage.
V_{DD}	V_{DD}	Power	—	Positive supply.
V_{SS}	V_{SS}	Power	—	Ground reference.

Legend: AN = Analog input or output; CMOS = CMOS compatible input or output; OD = Open Drain
TTL = TTL compatible input; ST = Schmitt Trigger input with CMOS levels; I^2C™ = Schmitt Trigger input with I^2C levels
HV = High Voltage; XTAL = Crystal

Note 1: Pin function is selectable via the APFCON register.
2: PIC16F1933 devices only.

TABLE 3-3: PIC16(L)F1933 MEMORY MAP, BANKS 0-7

BANK 0		BANK 1		BANK 2		BANK 3		BANK 4		BANK 5		BANK 6		BANK 7	
000h	INDF0	080h	INDF0	100h	INDF0	180h	INDF0	200h	INDF0	280h	INDF0	300h	INDF0	380h	INDF0
001h	INDF1	081h	INDF1	101h	INDF1	181h	INDF1	201h	INDF1	281h	INDF1	301h	INDF1	381h	INDF1
002h	PCL	082h	PCL	102h	PCL	182h	PCL	202h	PCL	282h	PCL	302h	PCL	382h	PCL
003h	STATUS	083h	STATUS	103h	STATUS	183h	STATUS	203h	STATUS	283h	STATUS	303h	STATUS	383h	STATUS
004h	FSR0L	084h	FSR0L	104h	FSR0L	184h	FSR0L	204h	FSR0L	284h	FSR0L	304h	FSR0L	384h	FSR0L
005h	FSR0H	085h	FSR0H	105h	FSR0H	185h	FSR0H	205h	FSR0H	285h	FSR0H	305h	FSR0H	385h	FSR0H
006h	FSR1L	086h	FSR1L	106h	FSR1L	186h	FSR1L	206h	FSR1L	286h	FSR1L	306h	FSR1L	386h	FSR1L
007h	FSR1H	087h	FSR1H	107h	FSR1H	187h	FSR1H	207h	FSR1H	287h	FSR1H	307h	FSR1H	387h	FSR1H
008h	BSR	088h	BSR	108h	BSR	188h	BSR	208h	BSR	288h	BSR	308h	BSR	388h	BSR
009h	WREG	089h	WREG	109h	WREG	189h	WREG	209h	WREG	289h	WREG	309h	WREG	389h	WREG
00Ah	PCLATH	08Ah	PCLATH	10Ah	PCLATH	18Ah	PCLATH	20Ah	PCLATH	28Ah	PCLATH	30Ah	PCLATH	38Ah	PCLATH
00Bh	INTCON	08Bh	INTCON	10Bh	INTCON	18Bh	INTCON	20Bh	INTCON	28Bh	INTCON	30Bh	INTCON	38Bh	INTCON
00Ch	PORTA	08Ch	TRISA	10Ch	LATA	18Ch	ANSELA	20Ch	—	28Ch	—	30Ch	—	38Ch	—
00Dh	PORTB	08Dh	TRISB	10Dh	LATB	18Dh	ANSELB	20Dh	WPUB	28Dh	—	30Dh	—	38Dh	—
00Eh	PORTC	08Eh	TRISC	10Eh	LATC	18Eh	—	20Eh	—	28Eh	—	30Eh	—	38Eh	—
00Fh	—	08Fh	—	10Fh	—	18Fh	—	20Fh	—	28Fh	—	30Fh	—	38Fh	—
010h	PORTE	090h	TRISE	110h	—	190h	—	210h	WPUE	290h	—	310h	—	390h	—
011h	PIR1	091h	PIE1	111h	CM1CON0	191h	EEADRL	211h	SSPBUF	291h	CCPR1L	311h	CCPR3L	391h	—
012h	PIR2	092h	PIE2	112h	CM1CON1	192h	EEADRH	212h	SSPADD	292h	CCPR1H	312h	CCPR3H	392h	—
013h	PIR3	093h	PIE3	113h	CM2CON0	193h	EEDATL	213h	SSPMSK	293h	CCP1CON	313h	CCP3CON	393h	—
014h	—	094h	—	114h	CM2CON1	194h	EEDATH	214h	SSPSTAT	294h	PWM1CON	314h	PWM3CON	394h	IOCBP
015h	TMR0	095h	OPTION_REG	115h	CMOUT	195h	EECON1	215h	SSPCON1	295h	CCP1AS	315h	CCP3AS	395h	IOCBN
016h	TMR1L	096h	PCON	116h	BORCON	196h	EECON2	216h	SSPCON2	296h	PSTR1CON	316h	PSTR3CON	396h	IOCBF
017h	TMR1H	097h	WDTCON	117h	FVRCON	197h	—	217h	SSPCON3	297h	—	317h	—	397h	—
018h	T1CON	098h	OSCTUNE	118h	DACCON0	198h	—	218h	—	298h	CCPR2L	318h	CCPR4L	398h	—
019h	T1GCON	099h	OSCCON	119h	DACCON1	199h	RCREG	219h	—	299h	CCPR2H	319h	CCPR4H	399h	—
01Ah	TMR2	09Ah	OSCSTAT	11Ah	SRCON0	19Ah	TXREG	21Ah	—	29Ah	CCP2CON	31Ah	CCP4CON	39Ah	—
01Bh	PR2	09Bh	ADRESL	11Bh	SRCON1	19Bh	SPBRGL	21Bh	—	29Bh	PWM2CON	31Bh	—	39Bh	—
01Ch	T2CON	09Ch	ADRESH	11Ch	—	19Ch	SPBRGH	21Ch	—	29Ch	CCP2AS	31Ch	CCPR5L	39Ch	—
01Dh	—	09Dh	ADCON0	11Dh	APFCON	19Dh	RCSTA	21Dh	—	29Dh	PSTR2CON	31Dh	CCPR5H	39Dh	—
01Eh	CPSCON0	09Eh	ADCON1	11Eh	—	19Eh	TXSTA	21Eh	—	29Eh	CCPTMRS0	31Eh	CCP5CON	39Eh	—
01Fh	CPSCON1	09Fh	—	11Fh	—	19Fh	BAUDCTR	21Fh	—	29Fh	CCPTMRS1	31Fh	—	39Fh	—
020h	General Purpose Register 80 Bytes	0A0h	General Purpose Register 80 Bytes	120h	General Purpose Register 80 Bytes	1A0h	Unimplemented Read as '0'	220h	Unimplemented Read as '0'	2A0h	Unimplemented Read as '0'	320h	Unimplemented Read as '0'	3A0h	Unimplemented Read as '0'
06Fh		0EFh		16Fh		1EFh		26Fh		2EFh		36Fh		3EFh	
070h	Common RAM	0F0h	Accesses 70h – 7Fh	170h	Accesses 70h – 7Fh	1F0h	Accesses 70h – 7Fh)	270h	Accesses 70h – 7Fh	2F0h	Accesses 70h – 7Fh	370h	Accesses 70h – 7Fh	3F0h	Accesses 70h – 7Fh
07Fh		0FFh		17Fh		1FFh		27Fh		2FFh		37Fh		3FFh	

Legend: = Unimplemented data memory locations, read as '0'.

TABLE 3-9: SPECIAL FUNCTION REGISTER SUMMARY (CONTINUED)

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR, BOR	Value on all other Resets
Bank 7											
380h(2)	INDF0	Addressing this location uses contents of FSR0H/FSR0L to address data memory (not a physical register)								xxxx xxxx	xxxx xxxx
381h(2)	INDF1	Addressing this location uses contents of FSR1H/FSR1L to address data memory (not a physical register)								xxxx xxxx	xxxx xxxx
382h(2)	PCL	Program Counter (PC) Least Significant Byte								0000 0000	0000 0000
383h(2)	STATUS	—	—	—	$\overline{TO}$	$\overline{PD}$	Z	DC	C	---1 1000	---q quuu
384h(2)	FSR0L	Indirect Data Memory Address 0 Low Pointer								0000 0000	uuuu uuuu
385h(2)	FSR0H	Indirect Data Memory Address 0 High Pointer								0000 0000	0000 0000
386h(2)	FSR1L	Indirect Data Memory Address 1 Low Pointer								0000 0000	uuuu uuuu
387h(2)	FSR1H	Indirect Data Memory Address 1 High Pointer								0000 0000	0000 0000
388h(2)	BSR	—	—	—	BSR<4:0>					---0 0000	---0 0000
389h(2)	WREG	Working Register								0000 0000	uuuu uuuu
38Ah(1, 2)	PCLATH	—	Write Buffer for the upper 7 bits of the Program Counter							-000 0000	-000 0000
38Bh(2)	INTCON	GIE	PEIE	TMR0IE	INTE	IOCIE	TMR0IF	INTF	IOCIF	0000 0000	0000 0000
38Ch	—	Unimplemented								—	—
38Dh	—	Unimplemented								—	—
38Eh	—	Unimplemented								—	—
38Fh	—	Unimplemented								—	—
390h	—	Unimplemented								—	—
391h	—	Unimplemented								—	—
392h	—	Unimplemented								—	—
393h	—	Unimplemented								—	—
394h	IOCBP	IOCBP7	IOCBP6	IOCBP5	IOCBP4	IOCBP3	IOCBP2	IOCBP1	IOCBP0	0000 0000	0000 0000
395h	IOCBN	IOCBN7	IOCBN6	IOCBN5	IOCBN4	IOCBN3	IOCBN2	IOCBN1	IOCBN0	0000 0000	0000 0000
396h	IOCBF	IOCBF7	IOCBF6	IOCBF5	IOCBF4	IOCBF3	IOCBF2	IOCBF1	IOCBF0	0000 0000	0000 0000
397h	—	Unimplemented								—	—
398h	—	Unimplemented								—	—
399h	—	Unimplemented								—	—
39Ah	—	Unimplemented								—	—
39Bh	—	Unimplemented								—	—
39Ch	—	Unimplemented								—	—
39Dh	—	Unimplemented								—	—
39Eh	—	Unimplemented								—	—
39Fh	—	Unimplemented								—	—

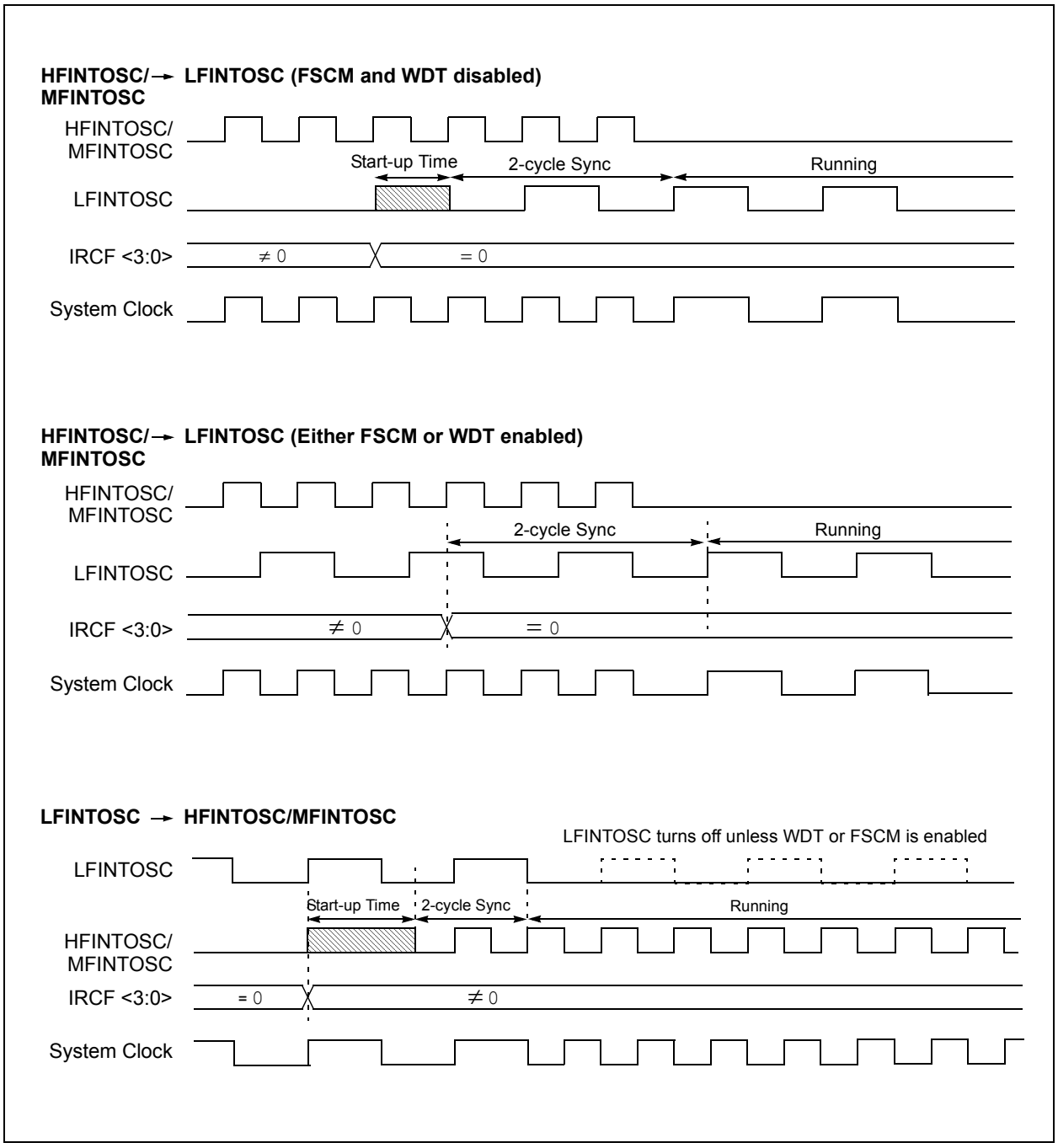
Legend: x = unknown, u = unchanged, q = value depends on condition, - = unimplemented, read as '0', r = reserved. Shaded locations are unimplemented, read as '0'.

Note 1: The upper byte of the program counter is not directly accessible. PCLATH is a holding register for the PC<14:8>, whose contents are transferred to the upper byte of the program counter.

2: These registers can be addressed from any bank.

3: Unimplemented, read as '1'.

FIGURE 5-7: INTERNAL OSCILLATOR SWITCH TIMING



11.0 DATA EEPROM AND FLASH PROGRAM MEMORY CONTROL

The Data EEPROM and Flash program memory are readable and writable during normal operation (full VDD range). These memories are not directly mapped in the register file space. Instead, they are indirectly addressed through the Special Function Registers (SFRs). There are six SFRs used to access these memories:

- EECON1
- EECON2
- EEDATL
- EEDATH
- EEADRL
- EEADRH

When interfacing the data memory block, EEDATL holds the 8-bit data for read/write, and EEADRL holds the address of the EEDATL location being accessed. These devices have 256 bytes of data EEPROM with an address range from 0h to 0FFh.

When accessing the program memory block, the EEDATH:EEDATL register pair forms a 2-byte word that holds the 14-bit data for read/write, and the EEADRL and EEADRH registers form a 2-byte word that holds the 15-bit address of the program memory location being read.

The EEPROM data memory allows byte read and write. An EEPROM byte write automatically erases the location and writes the new data (erase before write).

The write time is controlled by an on-chip timer. The write/erase voltages are generated by an on-chip charge pump rated to operate over the voltage range of the device for byte or word operations.

Depending on the setting of the Flash Program Memory Self Write Enable bits WRT<1:0> of the Configuration Words, the device may or may not be able to write certain blocks of the program memory. However, reads from the program memory are always allowed.

When the device is code-protected, the device programmer can no longer access data or program memory. When code-protected, the CPU may continue to read and write the data EEPROM memory and Flash program memory.

11.1 EEADRL and EEADRH Registers

The EEADRH:EEADRL register pair can address up to a maximum of 256 bytes of data EEPROM or up to a maximum of 32K words of program memory.

When selecting a program address value, the MSB of the address is written to the EEADRH register and the LSB is written to the EEADRL register. When selecting a EEPROM address value, only the LSB of the address is written to the EEADRL register.

11.1.1 EECON1 AND EECON2 REGISTERS

EECON1 is the control register for EE memory accesses.

Control bit EEPGD determines if the access will be a program or data memory access. When clear, any subsequent operations will operate on the EEPROM memory. When set, any subsequent operations will operate on the program memory. On Reset, EEPROM is selected by default.

Control bits RD and WR initiate read and write, respectively. These bits cannot be cleared, only set, in software. They are cleared in hardware at completion of the read or write operation. The inability to clear the WR bit in software prevents the accidental, premature termination of a write operation.

The WREN bit, when set, will allow a write operation to occur. On power-up, the WREN bit is clear. The WRERR bit is set when a write operation is interrupted by a Reset during normal operation. In these situations, following Reset, the user can check the WRERR bit and execute the appropriate error handling routine.

Interrupt flag bit EEIF of the PIR2 register is set when write is complete. It must be cleared in the software.

Reading EECON2 will read all ‘0’s. The EECON2 register is used exclusively in the data EEPROM write sequence. To enable writes, a specific pattern must be written to EECON2.

REGISTER 11-5: EECON1: EEPROM CONTROL 1 REGISTER

R/W-0/0	R/W-0/0	R/W-0/0	R/W/HC-0/0	R/W-x/q	R/W-0/0	R/S/HC-0/0	R/S/HC-0/0
EEPGD	CFGS	LWLO	FREE	WRERR	WREN	WR	RD
bit 7							bit 0

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
S = Bit can only be set	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	HC = Bit is cleared by hardware

bit 7 **EEPGD:** Flash Program/Data EEPROM Memory Select bit
- 1 = Accesses program space Flash memory
- 0 = Accesses data EEPROM memory

bit 6 **CFGS:** Flash Program/Data EEPROM or Configuration Select bit
- 1 = Accesses Configuration, User ID and Device ID Registers
- 0 = Accesses Flash Program or data EEPROM Memory

bit 5 **LWLO:** Load Write Latches Only bit

If CFGS = 1 (Configuration space) **OR** CFGS = 0 and EEPGD = 1 (program Flash):
- 1 = The next WR command does not initiate a write; only the program memory latches are updated.
- 0 = The next WR command writes a value from EEDATH:EEDATL into program memory latches and initiates a write of all the data stored in the program memory latches.

If CFGS = 0 and EEPGD = 0: (Accessing data EEPROM)
LWLO is ignored. The next WR command initiates a write to the data EEPROM.

bit 4 **FREE:** Program Flash Erase Enable bit

If CFGS = 1 (Configuration space) **OR** CFGS = 0 and EEPGD = 1 (program Flash):
- 1 = Performs an erase operation on the next WR command (cleared by hardware after completion of erase).
- 0 = Performs a write operation on the next WR command.

If EEPGD = 0 and CFGS = 0: (Accessing data EEPROM)
FREE is ignored. The next WR command will initiate both a erase cycle and a write cycle.

bit 3 **WRERR:** EEPROM Error Flag bit
- 1 = Condition indicates an improper program or erase sequence attempt or termination (bit is set automatically on any set attempt (write '1') of the WR bit).
- 0 = The program or erase operation completed normally.

bit 2 **WREN:** Program/Erase Enable bit
- 1 = Allows program/erase cycles
- 0 = Inhibits programming/erasing of program Flash and data EEPROM

bit 1 **WR:** Write Control bit
- 1 = Initiates a program Flash or data EEPROM program/erase operation. The operation is self-timed and the bit is cleared by hardware once operation is complete. The WR bit can only be set (not cleared) in software.
- 0 = Program/erase operation to the Flash or data EEPROM is complete and inactive.

bit 0 **RD:** Read Control bit
- 1 = Initiates an program Flash or data EEPROM read. Read takes one cycle. RD is cleared in hardware. The RD bit can only be set (not cleared) in software.
- 0 = Does not initiate a program Flash or data EEPROM data read.

REGISTER 12-5: ANSELA: PORTA ANALOG SELECT REGISTER

U-0	U-0	R/W-1/1	R/W-1/1	R/W-1/1	R/W-1/1	R/W-1/1	R/W-1/1
—	—	ANSA5	ANSA4	ANSA3	ANSA2	ANSA1	ANSA0
bit 7							bit 0

Legend:		
R = Readable bit	W = Writable bit	U = Unimplemented bit, read as '0'
u = Bit is unchanged	x = Bit is unknown	-n/n = Value at POR and BOR/Value at all other Resets
'1' = Bit is set	'0' = Bit is cleared	

bit 7-6 **Unimplemented:** Read as '0'

bit 5-0 **ANSA<5:0>**: Analog Select between Analog or Digital Function on pins RA<5:0>, respectively
0 = Digital I/O. Pin is assigned to port or digital special function.
1 = Analog input. Pin is assigned as analog input(1). Digital input buffer disabled.

Note 1: When setting a pin to an analog input, the corresponding TRIS bit must be set to Input mode in order to allow external control of the voltage on the pin.

14.0 FIXED VOLTAGE REFERENCE (FVR)

The Fixed Voltage Reference, or FVR, is a stable voltage reference, independent of VDD, with 1.024V, 2.048V or 4.096V selectable output levels. The output of the FVR can be configured to supply a reference voltage to the following:

- ADC input channel
- ADC positive reference
- Comparator positive input
- Digital-to-Analog Converter (DAC)
- Capacitive Sensing (CPS) module
- LCD bias generator

The FVR can be enabled by setting the FVREN bit of the FVRCON register.

14.1 Independent Gain Amplifiers

The output of the FVR supplied to the ADC, Comparators, DAC and CPS is routed through two independent programmable gain amplifiers. Each amplifier can be programmed for a gain of 1x, 2x or 4x, to produce the three possible voltage levels.

The ADFVR<1:0> bits of the FVRCON register are used to enable and configure the gain amplifier settings for the reference supplied to the ADC module. Reference **Section 15.0 "Analog-to-Digital Converter (ADC) Module"** for additional information.

The CDAFVR<1:0> bits of the FVRCON register are used to enable and configure the gain amplifier settings for the reference supplied to the DAC, CPS and Comparator module. Reference **Section 17.0 "Digital-to-Analog Converter (DAC) Module"**, **Section 18.0 "Comparator Module"** and **Section 26.0 "Capacitive Sensing (CPS) Module"** for additional information.

14.2 FVR Stabilization Period

When the Fixed Voltage Reference module is enabled, it requires time for the reference and amplifier circuits to stabilize. Once the circuits stabilize and are ready for use, the FVRRDY bit of the FVRCON register will be set. See in **Section 30.0 "Electrical Specifications"** for the minimum delay requirement.

TABLE 16-2: SUMMARY OF REGISTERS ASSOCIATED WITH THE TEMPERATURE INDICATOR

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on page
FVRCON	FVREN	FVRRDY	TSEN	TSRNG	CDAFVR<1:0>		ADFVR<1:0>		118

Legend: Shaded cells are unused by the temperature indicator module.

22.0 TIMER2/4/6 MODULES

There are up to three identical Timer2-type modules available. To maintain pre-existing naming conventions, the Timers are called Timer2, Timer4 and Timer6 (also Timer2/4/6).

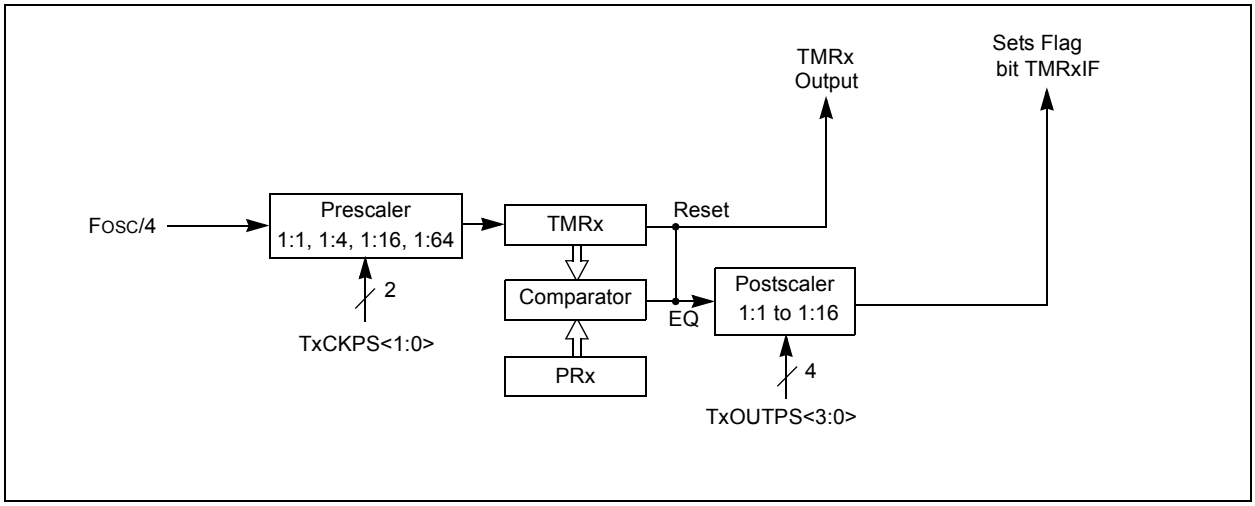
Note:	The 'x' variable used in this section is used to designate Timer2, Timer4, or Timer6. For example, TxCON references T2CON, T4CON, or T6CON. PRx references PR2, PR4, or PR6.

The Timer2/4/6 modules incorporate the following features:

- 8-bit Timer and Period registers (TMRx and PRx, respectively)
- Readable and writable (both registers)
- Software programmable prescaler (1:1, 1:4, 1:16, and 1:64)
- Software programmable postscaler (1:1 to 1:16)
- Interrupt on TMRx match with PRx, respectively
- Optional use as the shift clock for the MSSP module (Timer2 only)

See Figure 22-1 for a block diagram of Timer2/4/6.

FIGURE 22-1: TIMER2/4/6 BLOCK DIAGRAM



23.4.4 AUTO-RESTART MODE

The Enhanced PWM can be configured to automatically restart the PWM signal once the auto-shutdown condition has been removed. Auto-restart is enabled by setting the PxRSEN bit in the PWMxCON register.

If auto-restart is enabled, the CCPxASE bit will remain set as long as the auto-shutdown condition is active. When the auto-shutdown condition is removed, the CCPxASE bit will be cleared via hardware and normal operation will resume.

FIGURE 23-15: PWM AUTO-SHUTDOWN WITH AUTO-RESTART (PXRSEN = 1)

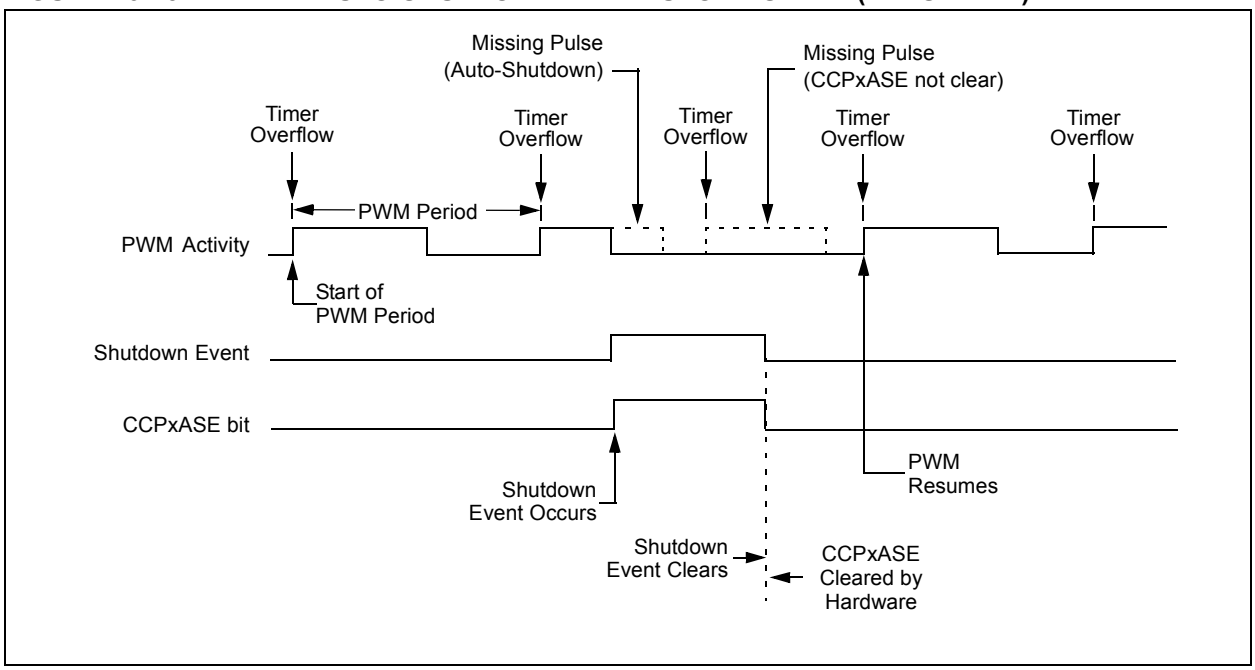


FIGURE 24-7: SPI DAISY-CHAIN CONNECTION

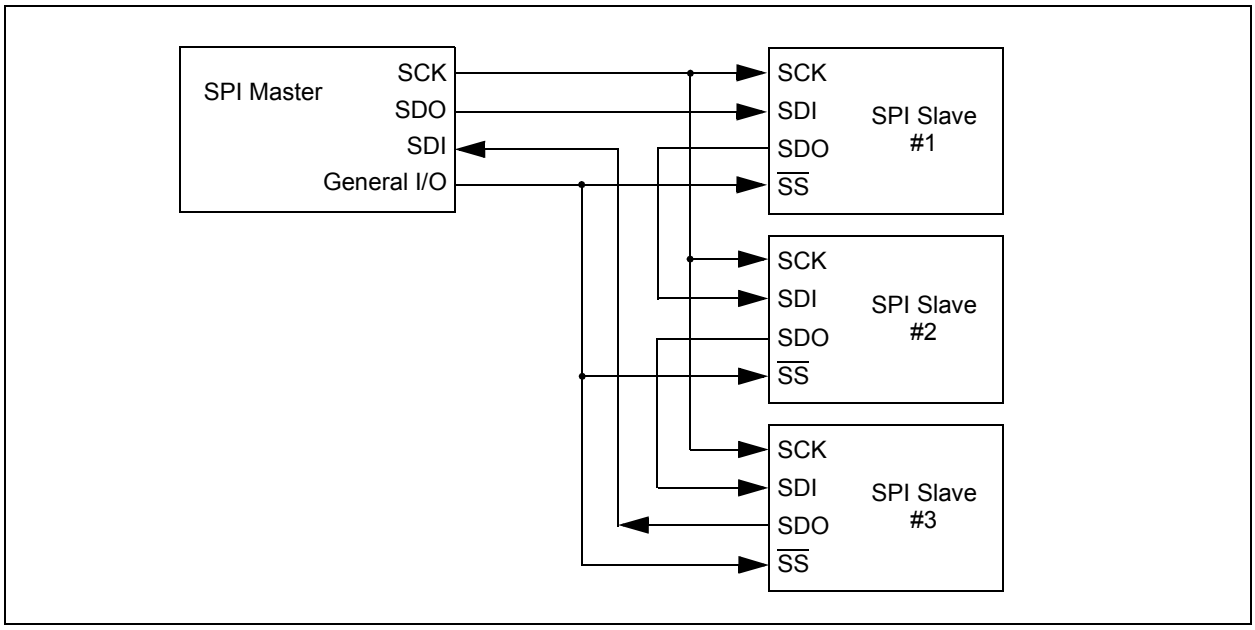


FIGURE 24-8: SLAVE SELECT SYNCHRONOUS WAVEFORM

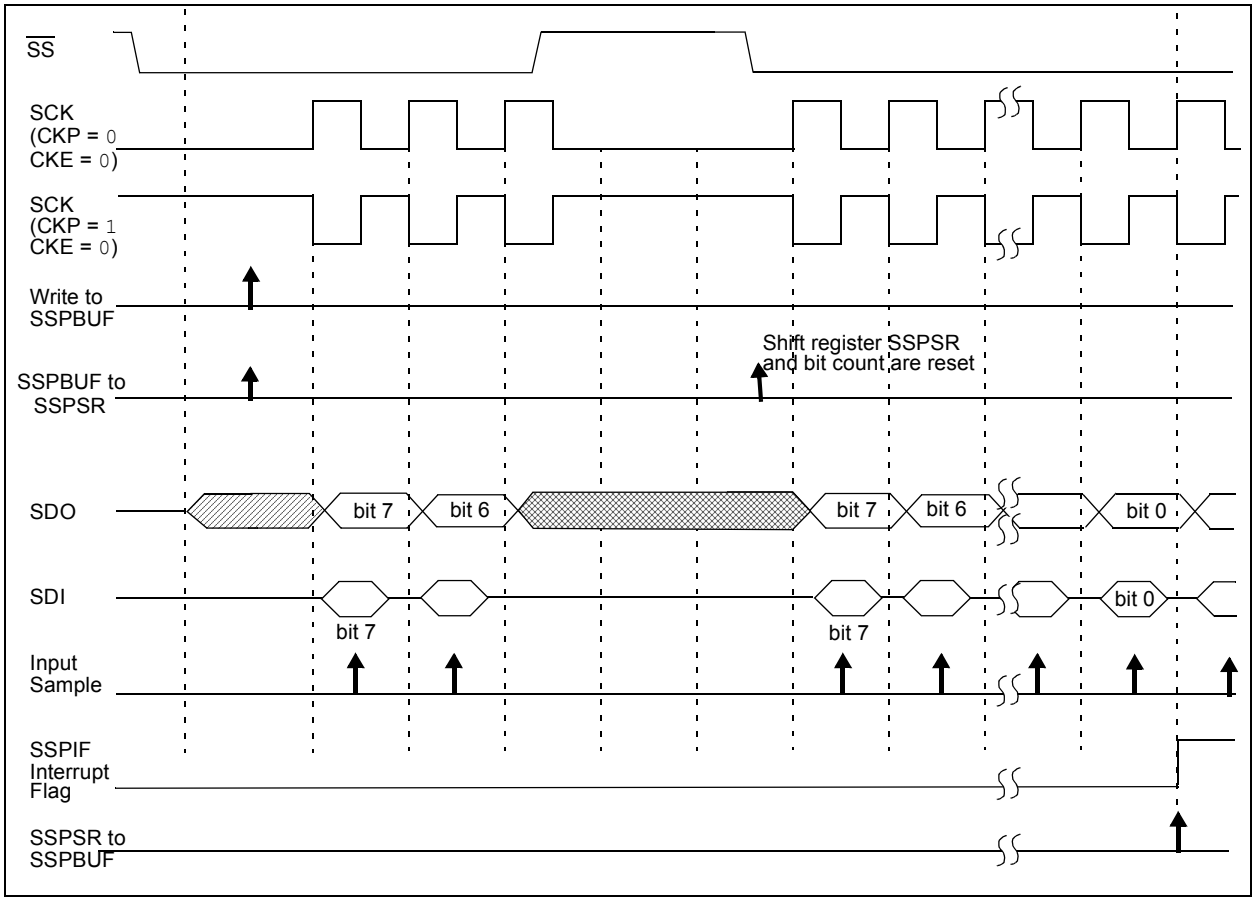
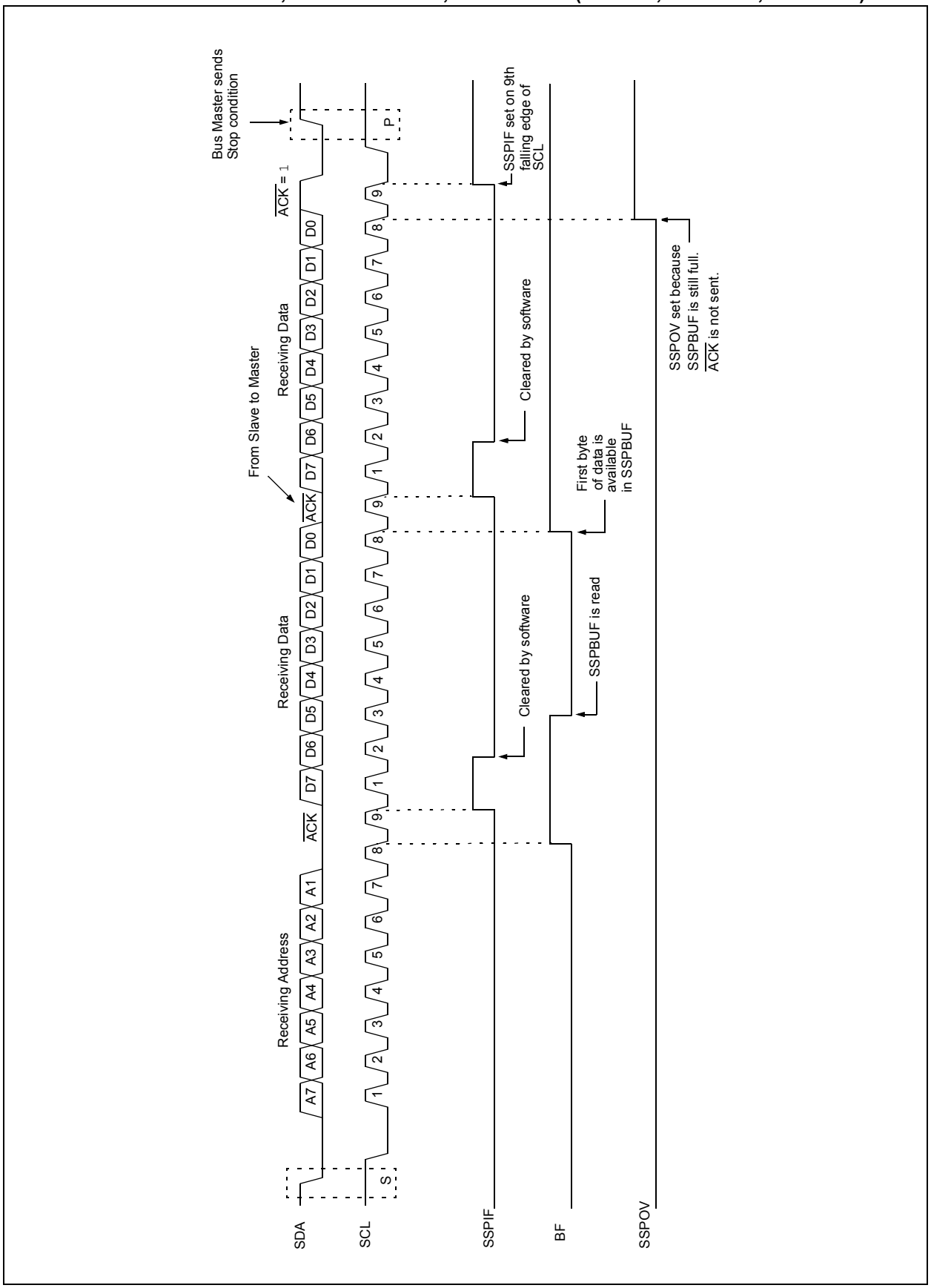


FIGURE 24-14: I²C SLAVE, 7-BIT ADDRESS, RECEPTION (SEN = 0, AHEN = 0, DHEN = 0)



26.1 Analog MUX

The CPS module can monitor up to 16 inputs. The capacitive sensing inputs are defined as CPS<15:0>. To determine if a frequency change has occurred the user must:

- Select the appropriate CPS pin by setting the CPSCH<2:0> bits of the CPSCON1 register.
- Set the corresponding ANSEL bit.
- Set the corresponding TRIS bit.
- Run the software algorithm.

Selection of the CPSx pin while the module is enabled will cause the capacitive sensing oscillator to be on the CPSx pin. Failure to set the corresponding ANSEL and TRIS bits can cause the capacitive sensing oscillator to stop, leading to false frequency readings.

26.2 Capacitive Sensing Oscillator

The capacitive sensing oscillator consists of a constant current source and a constant current sink, to produce a triangle waveform. The CPSOUT bit of the CPSCON0 register shows the status of the capacitive sensing oscillator, whether it is a sinking or sourcing current. The oscillator is designed to drive a capacitive load (single PCB pad) and at the same time, be a clock source to either Timer0 or Timer1. The oscillator has several different current settings as defined by CPSRNG<1:0> of the CPSCON0 register. The different current settings for the oscillator serve two purposes:

- Maximize the number of counts in a timer for a fixed time base.
- Maximize the count differential in the timer during a change in frequency.

26.3 Voltage Reference Modes

The capacitive sensing oscillator uses voltage references to provide two voltage thresholds for oscillation. The upper voltage threshold is referred to as Ref+ and the lower voltage threshold is referred to as Ref-.

The user can elect to use Fixed Voltage References, which are internal to the capacitive sensing oscillator, or variable voltage references, which are supplied by the Fixed Voltage Reference (FVR) module and the Digital-to-Analog Converter (DAC) module.

When the Fixed Voltage References are used, the V_{SS} voltage determines the lower threshold level (Ref-) and the V_{DD} voltage determines the upper threshold level (Ref+).

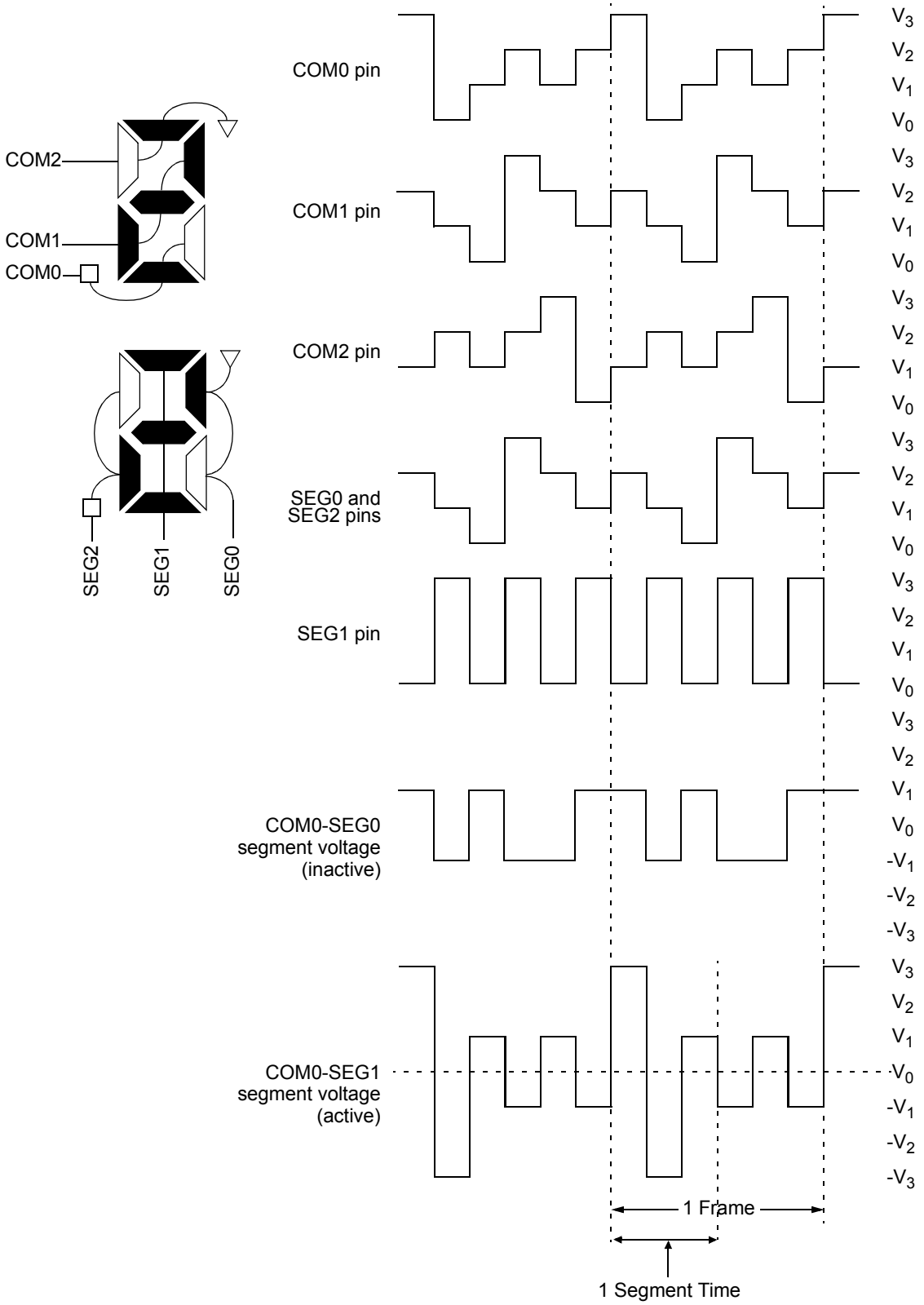
When the variable voltage references are used, the DAC voltage determines the lower threshold level (Ref-) and the FVR voltage determines the upper threshold level (Ref+). An advantage of using these reference sources is that oscillation frequency remains constant with changes in V_{DD}.

Different oscillation frequencies can be obtained through the use of these variable voltage references. The more the upper voltage reference level is lowered and the more the lower voltage reference level is raised, the higher the capacitive sensing oscillator frequency becomes.

Selection between the voltage references is controlled by the CPSRM bit of the CPSCON0 register. Setting this bit selects the variable voltage references and clearing this bit selects the fixed voltage references.

Please see **Section 14.0 "Fixed Voltage Reference (FVR)"** and **Section 17.0 "Digital-to-Analog Converter (DAC) Module"** for more information on configuring the variable voltage levels.

FIGURE 27-15: TYPE-A WAVEFORMS IN 1/3 MUX, 1/3 BIAS DRIVE



Note: 1 Frame = 2 single segment times.

27.13 Configuring the LCD Module

The following is the sequence of steps to configure the LCD module.

1. Select the frame clock prescale using bits LP<3:0> of the LCDPS register.
2. Configure the appropriate pins to function as segment drivers using the LCDSEn registers.
3. Configure the LCD module for the following using the LCDCON register:
   - Multiplex and bias mode, bits LMUX<1:0>
   - Timing source, bits CS<1:0>
   - Sleep mode, bit SLPEN
4. Write initial values to pixel data registers, LCDDATA0 through LCDDATA11.
5. Clear LCD Interrupt Flag, LCDIF bit of the PIR2 register and if desired, enable the interrupt by setting bit LCDIE of the PIE2 register.
6. Configure bias voltages by setting the LCDRL, LCDREF and the associated ANSELx registers as needed.
7. Enable the LCD module by setting bit LCDEN of the LCDCON register.

27.14 Disabling the LCD Module

To disable the LCD module, write all '0's to the LCDCON register.

27.15 LCD Current Consumption

When using the LCD module the current consumption consists of the following three factors:

- Oscillator Selection
- LCD Bias Source
- Capacitance of the LCD segments

The current consumption of just the LCD module can be considered negligible compared to these other factors.

27.15.1 OSCILLATOR SELECTION

The current consumed by the clock source selected must be considered when using the LCD module. See **Section 30.0 "Electrical Specifications"** for oscillator current consumption information.

27.15.2 LCD BIAS SOURCE

The LCD bias source, internal or external, can contribute significantly to the current consumption. Use the highest possible resistor values while maintaining contrast to minimize current.

27.15.3 CAPACITANCE OF THE LCD SEGMENTS

The LCD segments which can be modeled as capacitors which must be both charged and discharged every frame. The size of the LCD segment and its technology determines the segment's capacitance.

29.0 INSTRUCTION SET SUMMARY

Each instruction is a 14-bit word containing the operation code (opcode) and all required operands. The opcodes are broken into three broad categories.

- Byte Oriented
- Bit Oriented
- Literal and Control

The literal and control category contains the most varied instruction word format.

Table 29-3 lists the instructions recognized by the MPASM™ assembler.

All instructions are executed within a single instruction cycle, with the following exceptions, which may take two or three cycles:

- Subroutine takes two cycles (CALL, CALLW)
- Returns from interrupts or subroutines take two cycles (RETURN, RETLW, RETFIE)
- Program branching takes two cycles (GOTO, BRA, BRW, BTFSS, BTFSC, DECFSZ, INCSFZ)
- One additional instruction cycle will be used when any instruction references an indirect file register and the file select register is pointing to program memory.

One instruction cycle consists of 4 oscillator cycles; for an oscillator frequency of 4 MHz, this gives a nominal instruction execution rate of 1 MHz.

All instruction examples use the format '0xhh' to represent a hexadecimal number, where 'h' signifies a hexadecimal digit.

29.1 Read-Modify-Write Operations

Any instruction that specifies a file register as part of the instruction performs a Read-Modify-Write (R-M-W) operation. The register is read, the data is modified, and the result is stored according to either the instruction, or the destination designator 'd'. A read operation is performed on a register even if the instruction writes to that register.

TABLE 29-1: OPCODE FIELD DESCRIPTIONS

Field	Description
f	Register file address (0x00 to 0x7F)
W	Working register (accumulator)
b	Bit address within an 8-bit file register
k	Literal field, constant data or label
x	Don't care location (= 0 or 1). The assembler will generate code with x = 0. It is the recommended form of use for compatibility with all Microchip software tools.
d	Destination select; d = 0: store result in W, d = 1: store result in file register f. Default is d = 1.
n	FSR or INDF number. (0-1)
mm	Pre-post increment-decrement mode selection

TABLE 29-2: ABBREVIATION DESCRIPTIONS

Field	Description
PC	Program Counter
$\overline{TO}$	Time-out bit
C	Carry bit
DC	Digit carry bit
Z	Zero bit
$\overline{PD}$	Power-down bit

30.2 DC Characteristics: Supply Currents (I_{DD}) (Continued)

PIC16LF1933			Standard Operating Conditions (unless otherwise stated) Operating temperature -40°C ≤ TA ≤ +85°C for industrial -40°C ≤ TA ≤ +125°C for extended				
PIC16F1933			**Standard Operating Conditions (unless otherwise stated)** Operating temperature -40°C ≤ TA ≤ +85°C for industrial -40°C ≤ TA ≤ +125°C for extended				
Param No.	**Device Characteristics**	**Min.**	**Typ†**	**Max.**	**Units**	**Conditions**	
						VDD	**Note**
	Supply Current (I_{DD})(1, 2)						
D013		—	60	90	µA	1.8	FOSC = 500 kHz EC Oscillator Low-Power mode
		—	85	135	µA	3.0	
D013		—	60	137	µA	1.8	FOSC = 500 kHz EC Oscillator Low-Power mode **(Note 5)**
		—	85	194	µA	3.0	
		—	95	230	µA	5.0	
D014		—	300	340	µA	1.8	FOSC = 4 MHz EC Oscillator mode Medium-Power mode
		—	400	650	µA	3.0	
D014		—	350	375	µA	1.8	FOSC = 4 MHz EC Oscillator mode **(Note 5)** Medium-Power mode
		—	550	700	µA	3.0	
		—	600	900	µA	5.0	
D015		—	3.7	4.2	mA	3.0	FOSC = 32 MHz EC Oscillator High-Power mode
		—	4.2	5.2	mA	3.6	
D015		—	3.7	4.2	mA	3.0	FOSC = 32 MHz EC Oscillator High-Power mode **(Note 5)**
		—	3.9	4.7	mA	5.0	
D016		—	4	10	µA	1.8	FOSC = 32 kHz LFINTOSC mode, 85°C
		—	7	13	µA	3.0	
D016		—	27	61	µA	1.8	FOSC = 32 kHz LFINTOSC mode, 85°C **(Note 5)**
		—	33	74	µA	3.0	
		—	34	76	µA	5.0	

Note 1: The test conditions for all I_{DD} measurements in active operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tri-stated, pulled to VDD; $\overline{MCLR}$ = VDD; WDT disabled.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors, such as I/O pin loading and switching rate, oscillator type, internal code execution pattern and temperature, also have an impact on the current consumption.

3: For RC oscillator configurations, current through REXT is not included. The current through the resistor can be extended by the formula $I_R = V_{DD}/2R_{EXT}$ (mA) with REXT in kΩ.

4: FVR and BOR are disabled.

5: 0.1 µF capacitor on VCAP.

6: 8 MHz crystal oscillator with 4x PLL enabled.

R

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NOTES: